SGS-THOMSON MICROELECTRONICS

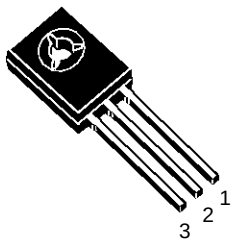
MJE210

SILICON PNP TRANSISTOR

- SGS-THOMSON PREFERRED SALESTYPE
- PNP TRANSISTOR

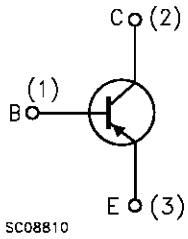
DESCRIPTION

The MJE210 is a silicon epitaxial-base PNP transistor in Jedec SOT-32 plastic package, designed for low voltage, low power, high gain aydio amplifier applications.



SOT-32

INTERNAL SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage (IE = 0)	-40	V
V_{CEO}	Collector-Emitter Voltage (I_B = 0)	-25	V
V_{EBO}	Base-Emitter Voltage (IC = 0)	-8	V
I_C	Collector Current	-5	A
I_{CM}	Collector Peak Current	-10	A
I_B	Base Current	-1	A
P_{tot}	Total Power Dissipation at $T_{case} \leq 25\ ^oC$ at $T_{amb} \leq 25\ ^oC$	15 1.5	W
T_{stg}	Storage Temperature	-65 to 150	^oC
T_j	Max Operating Junction Temperature	150	^oC

THERMAL DATA

$R_{thj\text{-}amb}$	Thermal Resistance Junction-ambient	Max	83.4	$^oC/W$
$R_{thj\text{-}case}$	Thermal Resistance Junction-case	Max	8.34	$^oC/W$

ELECTRICAL CHARACTERISTICS (T_{case} = 25 ^oC unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector Cut-off Current (I_E = 0)	V_{CB} = -40 V V_{CB} = -40 V T_{CASE} = 125^oC			-100 -100	nA µA
I_{EBO}	Emitter Cut-off Current (I_C = 0)	V_{EB} = -8 V			-100	nA
$V_{CEO(sus)}$*	Collector-Emitter Sustaining Voltage	I_C = -10 mA	-25			V
$V_{CE(sat)}$*	Collector-Emitter Sustaining Voltage	I_C = -0.5 A I_B = -50 mA I_C = -2 A I_B = -0.2 A I_C = -5 A I_B = -1 A			-0.3 -0.75 -1.8	V V V
$V_{BE(sat)}$*	Base-Emitter on Voltage	I_C = -5 A I_B = -1 A			-2.5	V
V_{BE}*	Base-Emitter on Voltage	I_C =- 2 A V_{CE} = -1 V			-1.6	V
h_{FE}*	DC Current Gain	I_C = -0.5 A V_{CE} = -1 V I_C = -2 A V_{CE} = -1 V I_C = -5 A V_{CE} = -2 V	70 45 10		180	
f_T	Transistor Frequency	I_C = 0.1 A V_{CE} = 10 V f = 10 MHz	65			MHz
C_{CBO}	Collector-base Capacitance	V_{CB} = -10 V I_E = 0 f = 0.1 MHz			120	pF

* Pulsed: Pulse duration = 300µs, duty cycle ≤ 1.5%

SOT-32 (TO-126) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	7.4		7.8	0.291		0.307
B	10.5		10.8	0.413		0.445
b	0.7		0.9	0.028		0.035
b1	0.49		0.75	0.019		0.030
C	2.4		2.7	0.040		0.106
c1	1.0		1.3	0.039		0.050
D	15.4		16.0	0.606		0.629
e		2.2			0.087	
e3	4.15		4.65	0.163		0.183
F		3.8			0.150	
G	3		3.2	0.118		0.126
H			2.54			0.100
H2		2.15			0.084